NSN 5961-00-420-0029

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-420-0029 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Current Rating Per Characteristic:** 1440.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Reference Number Differentiating Characteristics:** As differentiated by material will be in accordance with ships parts control center activity hx quality control, manufacturing and testing specifications Shelf Life: N/a **Unit Of Measure: Demilitarization:**